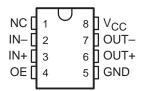
SLCS002C - JUNE 1983 - REVISED AUGUST 2000

- Operates From a Single 5-V Supply
- 0 to 5.5 V Common-Mode Input Voltage Range
- Self-Biased Inputs
- Complementary 3-State Outputs
- Enable Capability
- Hysteresis . . . 5 mV Typ
- Response Times . . . 25 ns Typ

# D, P, OR PS PACKAGE (TOP VIEW)



NC-No internal connection

### description

The TL712 is a high-speed comparator fabricated with bipolar Schottky process technology. The circuit has differential analog inputs and complementary 3-state TTL-compatible logic outputs with symmetrical switching characteristics. When the output enable (OE) is low, both outputs are in the high-impedance state. This device operates from a single 5-V supply and is useful as a disk memory read-chain data comparator.

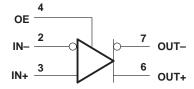
The TL712C is characterized for operation from 0°C to 70°C.

#### **AVAILABLE OPTIONS**

	PACKAGED DEVICES			
TA	PLASTIC SMALL OUTLINE (D)	PLASTIC SMALL-OUTLINE EIAJ (PS)	PLASTIC DIP (P)	
0°C to 70°C	TL712CD	TL712CPSR	TL712CP	

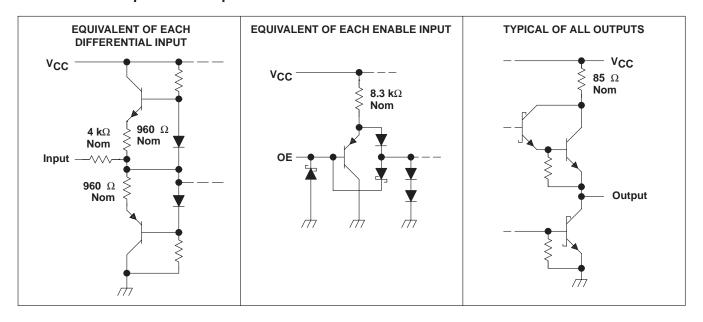
The PS package is only available tape and reeled. The D package also is available taped and reeled. Add the suffix R to device type (e.g., TL712CDR).

## symbol (positive logic)





### schematics of inputs and outputs



## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V <sub>CC</sub> (see Note 1)	
Differential input voltage, V <sub>ID</sub> (see Note 2)	
Input voltage, V <sub>I</sub> , any differential input	±25 V
Output enable voltage	
Low-level output current, I <sub>OL</sub>	50 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 3): D package	97°C/W
P package	e 85°C/W
PS packa	ge 95°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 10 sec	conds 260°C
Storage temperature range, T <sub>stg</sub>	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the "recommended operating conditions" section of this specification is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the network ground.
  - 2. Differential voltage values are at IN+ with respect to IN-.
  - 3. The package thermal impedance is calculated in accordance with JESD 51.



## recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V <sub>CC</sub>	4.75	5	5.25	V
Common-mode input voltage, V <sub>IC</sub>	0		5.5	V
High-level output current, IOH			-1	mA
Low-level output current, IOL			16	mA
Operating free-air temperature, TA	0		70	°C

## electrical characteristics at $V_{CC}$ = 5 V, $T_{A}$ = 25 $^{\circ}C$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VT	Threshold voltage ( $V_{T+}$ and $V_{T-}$ )	V <sub>ICR</sub> = 0 to 5 V	-100†		100	mV
V <sub>hys</sub>	Hysteresis (V <sub>T+</sub> – V <sub>T</sub> _)			5		mV
Vон	High-level output voltage	$V_{ID} = 100 \text{ mV}, \qquad I_{OH} = -1 \text{ mA}$	2.7	3.5		V
VOL	Low-level output voltage	$V_{ID} = -100 \text{ mV},  I_{OL} = 16 \text{ mA}$		0.4	0.5	V
loz	Off-state output current	V <sub>O</sub> = 2.4 V			-20	μΑ
Ц	Enable current	V <sub>I</sub> = 5.5 V			100	μΑ
IIH	High-level enable current	V <sub>IH</sub> = 2.7 V			20	μΑ
Ι <sub>Ι</sub> L	Low-level enable current	V <sub>IL</sub> = 0.4 V			-360	μΑ
rį	Differential input resistance		4			kΩ
r <sub>O</sub>	Output resistance				100	W
los	Short-circuit output current		-15		-85	mA
ICC	Supply current	V <sub>ID</sub> = 0, No load		17	20	mA

<sup>†</sup> The algebraic convention, where the more negative limit is designated as minimum, is used in this data sheet for input threshold voltage levels only.

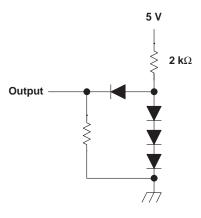
## switching characteristics, $V_{CC}$ = 5 V, $T_A$ = 25°C

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
tPLH	Propagation delay time, low-to-high-level output	TTL load,	pad, See Figure 1,	See Note 4		25		ns
tPHL	Propagation delay time, high-to-low-level output					25		ns

NOTE 4: The response time specified is for a 100-mV input step with 5-mV overdrive (105 mV total), and is the interval between the input step function and the instant when the output crosses 2.5 V.



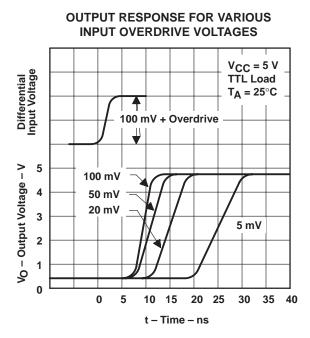
### PARAMETER MEASUREMENT INFORMATION



NOTE A: All diodes are 1N4148 or equivalent.

Figure 1. TTL Output Load Circuit

### TYPICAL CHARACTERISTICS





### INPUT OVERDRIVE VOLTAGES V<sub>CC</sub> = 5 V TTL Load Differential Input Voltage T<sub>A</sub> = 25°C 100 mV + Overdrive Vo - Output Voltage - V 5 4 100 mV 50 mV 3 5 mV 20 mV 2 0 0 5 10 15 20 25 30 35 t - Time - ns

**OUTPUT RESPONSE FOR VARIOUS** 

Figure 3



## **TYPICAL CHARACTERISTICS**

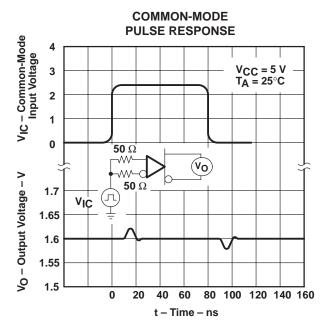


Figure 4

#### **IMPORTANT NOTICE**

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgment, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

Customers are responsible for their applications using TI components.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

Copyright © 2000, Texas Instruments Incorporated